

HIGH EFFICIENCY RECTIFIERS

VOLTAGE RANGE: 50--- 1000 V CURRE

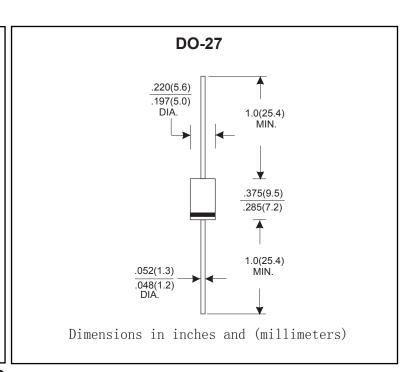
CURRENT: 3.0 A

FEATURES

- The plastic package carries Underwrites Laboratory
 Flammability Classification 94V-0
- High reliability
- Low forward voltage drop
- •Low power loss, high efficiency
- High forward surge current capability
- High temperature soldering guaranteed: 260 C/10 seconds at terminals
- Component in accordance to RoHs 2002/95/EC and WEEE 2002/96/EC

MECHANICAL DATA

- Case style: DO-27 plastic molded
- •Terminals: Axial lead ,solderable per MIL- STD-202,Method 208
- Polarity:Color band denotes cathode end
- Mounting Position:Any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		HER	HER	HER	HER	HER	HER	HER	HER	UNITS	
		301	302	303	304	305	306	307	308		
Maximum recurrent peak reverse voltage $V_{\scriptscriptstyle R}$		V_{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS voltage		V _{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC blocking voltage		V _{DC}	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current.375"(9.5mm) Lead Length at Ta=55 $^{\circ}\mathrm{C}$		I _{F(AV)}	3.0								А
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)		I _{FSM}	150.0								А
Maximum Instantaneous Forward Voltage at 2.0A		V _F		1.0		1	.3		1.7		V
Maximum reverse current	@T _A =25		10.0 150.0								μА
at rated DC blocking voltage	@T _A =100	- I _R									
Maximum reverse recovery time (Note1)		t _{rr}	50					75		ns	
Typical junction capacitance (Note2)		C	70					50		pF	
Typical thermal resistance		R _{0JA}	30								°C/W
Operating junction temperature range		Tj	- 55 + 125								$^{\circ}$
Storage temperature range		T _{STG}	- 55 + 150								$^{\circ}$

^{1.} Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal Resistance from Junction to Ambient. 375" (9.5 mm) lead length.



RATINGS AND CHARACTERISTIC CURVES

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

I0 Ω 50 Ω NONINDUCTIVE NONINDUCTIVE +0.5A (+) PULSE D.U.T. GENERATOR 50Vdc (NOTE2) (APPROX) -0. 25A (-)IΩOSCILLOSCOPE NONIN-Ф (NOTEI) DUCTIVE NOTES:1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1M 2.RISE TIME = 10ns MAX.SOURCE IMPEDANCE=50 -1. 0A → 1 cm | **←** SET TIME BASE FOR 50/100 ns/cm

FIG.2 -- FORWARD DERATING CURVE

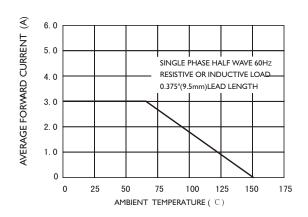


FIG.3 -- TYPICAL FORWARD CHARACTERISTIC

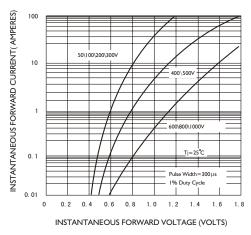


FIG.4 TYPICAL REVERSE CHARACTERISTIC

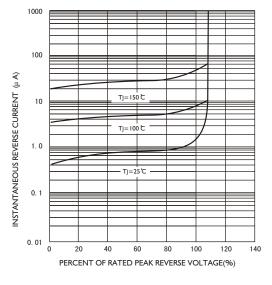


FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

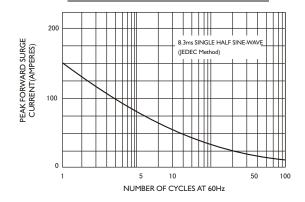


FIG.6-TYPICAL JUNCTION CAPACITANCE

